

1. [50 points] (npn parameters)

- a) For the 2N3904 set the Q-point $I_C=2\text{mA}$ and $V_{CE}=3\text{V}$. Calculate I_B . Calculate using the formulas of the book the grounded emitter low frequency admittance parameters g_π , g_m , g_o , and draw the small signal equivalent circuit adding in the base-emitter capacitance C_π . Give the 2-port admittance matrix, $Y(s)$.
- b) Run PSpice to get the I_C versus V_{CE} with I_B as a parameter so that the Q-point is available. From these curves determine the low frequency Y matrix parameters and compare with those found in part a).
- c) Compare the results of a) and b) with those of a data sheet.

2. [50 points] (pnp parameters)

- a) Repeat problem 1 for the pnp transistor 2N3906

3. [50 points] (push pull operation)

- a) Connect the 2N3904 & 2N3906 in the push-pull configuration of Figure 14.5, p. 1236 using $V_{CC}=9\text{V}$ and $R_L=10\Omega$. Do a DC run in PSpice to obtain a transfer curve similar to that of Figure 14.6.
- b) Use the pi-equivalent circuits and obtain the output resistance of the push-pull amplifier. Use the bias point found from part a) when the input voltage is zero (that is, at ground potential). Compare your results with those of the text.
- c) Use the circuit of Figure 14.14 where D1 is a diode connected QN and D2 is a diode connected QP and run PSpice to get a transfer curve; compare with that of part a).